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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Group Art Offic	20
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Complete if Known **Application Number** 10/676,969 Filing Date 09/30/2003 Gupta, et al. First Named Inventor Group Art Unit 2814 go, Ngan V. 2003P12642US Attorney Docket Number

Examiner Initials*		U.S. Patent Do	cument		Date of Publication of	Pages, Columns, Lines,
	Cite No.1	Number	Kind Code <sup>2</sup> (if known)	of Cited Document	Cited Document MM-DD-YYYY	Where Relevant Passages or Relevant Figures Appear
PP		6,274,979	1	Celii et al.		
2		6,580,213		Yamazaki		
hh		6,586,764		Buechel et al.		
	+ +					
				<u> </u>		<u>:</u>

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		OTHER NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cita No.1	Include name of the euthor (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	La
<b>4</b> %	Α	S.M. Sze, "Physics of Semiconductor Devices", 2 <sup>nd</sup> Edition, 1981, Pgs. 270-273 and 516-531	
hh	В	"Voltage Reduction in Organic Light-Emitting Diodes", L.S. Hung, M.G. Mason, Applied Physics Letters, Volume 78, Number 23, June 2, 2001, Pgs. 3732-3734	
hy	С	"Enhanced Hole Injection in a Bilayer Vacuum-Deposited Organic Light-Emitting Device Using a <i>P</i> -Type Doped Silicon Anode", X. Zhou, J. He, L. S. Liao, M. Lu, Z. H. Xiong, X.M. Ding, X. Y. Hou, F.G. Tao, C.E. Zhou and S.T. Lee, Applied Physics Letters, Volume 74, Number 4, January 25, 1999, Pgs. 609-611	

Examiner	- N 1 - / - N	Date	2 14 -11 6
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup>Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document, by the two-

letter code (WIPO Standard ST.3). \*For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial

number of the patent document. Skind of document by the appropriate symbols as Indicated on the document under WIPO Standard ST. 16 if

possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.